Unitized Semiconductor Devices - Page 1 of 2



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## Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

Between 0.250 inches and 0.450 inches

#### **Overall Width:**

1.050 inches

#### **Function For Which Designed:**

Rectifier

## Mounting Facility Quantity:

#### 2

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

#### Cathode

**Component Name And Quantity:** 

2 semiconductor device diode

#### **Mounting Method:**

Unthreaded hole

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon all semiconductor device diode

## Voltage Rating In Volts Per Characteristic:

45.0 working peak reverse voltage all semiconductor device diode and 45.0 reverse voltage, instantaneous all semiconductor device diode

## **Current Rating Per Characteristic:**

30.00 amperes forward current, average absolute all semiconductor device diode and 500.00 amperes forward current, average preset all semiconductor device diode

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

All semiconductor device diode junction pattern arrangement: pn

# Special Test Features:

Selected and tested for the milstar Irip program

# Test Data Document:

49956-g309036 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

2 pin and 1 case

## Shelf Life:

N/a

# Unit Of Measure:



Demilitarization:

No

Fiig:

A110a0